

# **MMBT3904**

# SMALL SIGNAL NPN TRANSISTOR

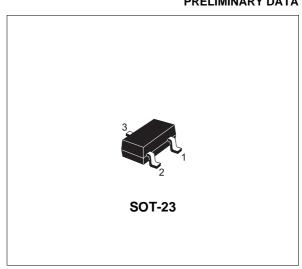
#### **PRELIMINARY DATA**

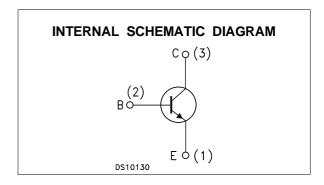
Туре	Marking
MMBT3904	34

- SILICON EPITAXIAL PLANAR NPN TRANSISTOR
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE AND REEL PACKING
- THE PNP COMPLEMENTARY TYPE IS MMBT3906

#### **APPLICATIONS**

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTOR WITH HIGH GAIN AND LOW SATURATION VOLTAGE





### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage (I <sub>E</sub> = 0)	60	V
$V_{CEO}$	Collector-Emitter Voltage (I <sub>B</sub> = 0)	40	V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	6	V
Ic	Collector Current	200	mA
P <sub>tot</sub>	Total Dissipation at T <sub>C</sub> = 25 °C	350	mW
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

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### THERMAL DATA

R <sub>thj-amb</sub> •	Thermal Resistance Junction-Ambient	Max	357.1	°C/W	
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<sup>•</sup> Device mounted on a PCB area of 1 cm<sup>2</sup>

## **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{o}C$ unless otherwise specified)

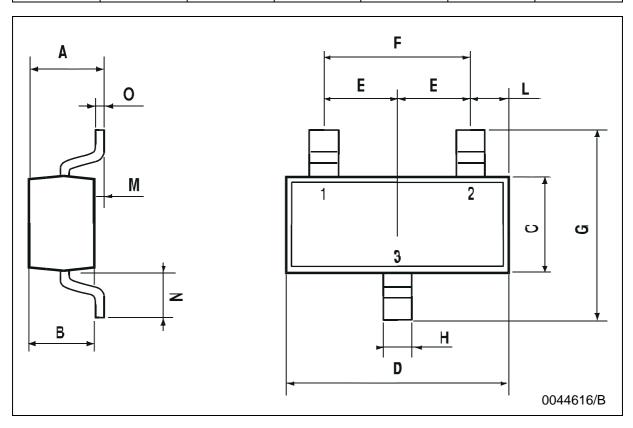
Symbol	Parameter	Test Conditions Mir		Min. Typ.		Unit	
I <sub>CEX</sub>	Collector Cut-off Current (V <sub>BE</sub> = -3 V)	V <sub>CE</sub> = 30 V			50	nA	
IBEX	Base Cut-off Current (V <sub>BE</sub> = -3 V)	VCE = 30 V			50	nA	
V <sub>(BR)CEO*</sub>	Collector-Emitter Breakdown Voltage (IB = 0)	I <sub>C</sub> = 1 mA	40			V	
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = 10 μA	60			V	
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage (I <sub>C</sub> = 0)	ΙΕ = 10 μΑ	6			V	
V <sub>CE(sat)*</sub>	Collector-Emitter Saturation Voltage	$\begin{split} I_C &= 10 \text{ mA} & I_B = 1 \text{ mA} \\ I_C &= 50 \text{ mA} & I_B = 5 \text{ mA} \end{split}$			0.2 0.2	V V	
V <sub>BE(sat)*</sub>	Base-Emitter Saturation Voltage	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	0.65		0.85 0.95	V V	
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 0.1 mA	60 80 100 60 30		300		
f⊤	Transition Frequency	$I_{C} = 10 \text{ mA} \text{ V}_{CE} = 20 \text{ V} \text{ f} = 100 \text{ MHz}$	250	270		MHz	
ССВО	Collector-Base Capacitance	I <sub>E</sub> = 0 V <sub>CB</sub> = 10 V f = 1 MHz		4		pF	
СЕВО	Emitter-Base Capacitance	$I_C = 0$ $V_{EB} = 0.5$ $V$ $f = 1MHz$		18		pF	
NF	Noise Figure	$V_{CE}$ = 5 $V$ $I_{C}$ = 0.1 mA $f$ = 10 Hz to 15.7 KHz $R_{G}$ = 1 $K\Omega$		5		dB	
t <sub>d</sub> t <sub>r</sub>	Delay Time Rise Time	$I_C = 10 \text{ mA}$ $I_B = 1 \text{ mA}$ $V_{CC} = 30 \text{ V}$			35 35	ns ns	
t <sub>s</sub>	Storage Time Fall Time	$I_{C} = 10 \text{ mA}$ $I_{B1} = -I_{B2} = 1 \text{ mA}$ $V_{CC} = 30 \text{ V}$			200 50	ns ns	

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 %

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## **SOT-23 MECHANICAL DATA**

DIM.	mm			mils		
Diw.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	0.85		1.1	33.4		43.3
В	0.65		0.95	25.6		37.4
С	1.20		1.4	47.2		55.1
D	2.80		3	110.2		118
E	0.95		1.05	37.4		41.3
F	1.9		2.05	74.8		80.7
G	2.1		2.5	82.6		98.4
Н	0.38		0.48	14.9		18.8
L	0.3		0.6	11.8		23.6
М	0		0.1	0		3.9
N	0.3		0.65	11.8		25.6
0	0.09		0.17	3.5		6.7



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